

EAMCET CODE: INDI









(Formerly RVR Institute of Engineering & Technology)

An Autonomous Institution Under UGC

NAAC Accredited. Recognized Under 2(f) of UGC Act 1956

Approved by AICTE, New Delhi, & Affiliated to JNTUH, Hyderabad.

JNTUH CODE: X3

COURSE FILE

ON

APPLIED PHYSICS LAB

Course Code - AP205BS

IB. Tech Semester-II

A.Y. 2022-2023

Prepared by

Mrs. B. SANTHI

Asst. Professor

Head of the Department
Department of H&S
SRI INDU INSTITUTE OF ENGG & TECH

heriauda(M) Ibrahimoatnam (M) R.R. Dist-501 516

PRINCIPAL

Sri Indu Institute of Engineering & Tecr. Sheriguda(Vill), Ibrahimpatnam R.R. Dist. Telangana-501 510.



EAMCET CODE: INDI









(Formerly RVR Institute of Engineering & Technology)

An Autonomous Institution Under UGC

NAAC Accredited. Recognized Under 2(f) of UGC Act 1956

Approved by AICTE, New Delhi, & Affiliated to JNTUH, Hyderabad.

JNTUH CODE: X3

Name of the Physical	
laboratory:	APPLIED PHYSICS LAB
Course code	AP205BS
Room No	B-201 & D-106
Name of the lab in charge	B. SANTHI
Name of the faculty in charge	B. SANTHI

Index of Lab File

S. No.	Name of the content
1	Institute vision and mission
2	Programme outcomes
3	Course Syllabus with Structure
4	Course Outcomes (CO) and CO-PO mapping
5	List of experiments and their CO, PO mapping
6	Time table
7	Model Practical End examination questions
8	Schedule of end practical examinations
9	List of examiners
10	Lab occupancy chart
11	Dos and Don'ts
12	Physical lab floor plan with area in Sq. m
13	Lab manual
14	CO-PO Attainments



Main Road, Sheriguda, Ibrahimpatnam, R.R. Dist. 501 510, Telangana. Campus Ph: 9640590999, 9347187999.





EAMCET CODE: INDI

Sri Indu Institute of Engineering and Technology (Autonomous)

(Formerly RVR Institute of Engineering & Technology)

An Autonomous Institution Under UGC

NAAC Accredited. Recognized Under 2(f) of UGC Act 1956

Approved by AICTE, New Delhi, & Affiliated to JNTUH, Hyderabad.

JNTUH CODE: X3

INSTITUTE VISION & MISSION

Vision:

To become a premier institute of academic excellence by providing the world class education that transforms individuals into high intellectuals, by evolving them as empathetic and responsible citizens through continuous improvement.

Mission:

- > **IM1:** To offer outcome-based education and enhancement of technical and practical skills.
- ➤ IM2: To Continuous assess of teaching-learning process through institute-industry collaboration.
- ➤ IM3: To be a Centre of excellence for innovative and emerging fields in technology development with state-of-art facilities to faculty and students' fraternity.
- ➤ **IM4:** To Create an enterprising environment to ensure culture, ethics and social responsibility among the stakeholder

Head of the Department Department of H&S

SRI INDU INSTITUTE OF ENGG & TECH

heriouda(M) Ibrahimpatnam (M) R.R. Dist-501 516

PRINCIPAL

Sri Indu Institute of Engineering & Tecr. Sheriguda(Vill), Ibrahimpatnam

R.R. Dist. Telangana-501 510.



(An Autonomous Institution under UGC)

Accredited by NAAC with A+ Grade, Recognized under 2(f) of UGC Act 1956.

(Approved by AICTE, New Delhi and Affiliated to JNTUH, Hyderabad

Khalsa Ibrahimpatnam, Sheriguda(V), Ibrahimpatnam(M), Ranga Reddy Dist., Telangana – 501 510

https://siiet.ac.in/

PROGRAM OUTCOMES

PO1: **ENGINEERING KNOWLEDGE**: Apply the knowledge of mathematics, science, engineering fundamentals, and an engineering specialization to the solution of complex engineering problems.

PO2: **PROBLEM ANALYSIS**: Identify, formulate, research literature, and analyze complex engineering problems reaching substantiated conclusions using first principles of mathematics, natural sciences, and engineering sciences.

PO3: **DESIGN/DEVELOPMENT OF SOLUTIONS**: Design solutions for complex engineering problems and design system components or processes that meet the specified needs with appropriate consideration for the public health and safety, and the cultural, societal, and environmental considerations.

PO4: **CONDUCT INVESTIGATIONS OF COMPLEX PROBLEMS**: Use research-based knowledge and research methods including design of experiments, analysis and interpretation of data, and synthesis of the information to provide valid conclusions.

PO5: **MODERN TOOL USAGE**: Create, select, and apply appropriate techniques, resources, and modern engineering and IT tools including prediction and modelling to complex engineering activities with an understanding of the limitations.

PO6: **THE ENGINEER AND SOCIETY**: Apply reasoning informed by the contextual knowledge to associate, health, safety, legal and cultural issues and the consequent responsibilities relevant to the professional engineering practice.

PO7: **ENVIRONMENT AND SUSTAINABILITY**: Understand the impact of the professional engineering solutions in societal and environmental contexts, and demonstrate the knowledge of, and need for sustainable development.

PO8: **ETHICS**: Apply ethical principles and commit to professional ethics and responsibilities and norms of the engineering practice.

PO9: **INDIVIDUAL AND TEAM WORK**: Function effectively as an individual, and as a member or leader in diverse teams, and in multidisciplinary settings.

PO10: **COMMUNICATION**: Communicate effectively on complex engineering activities with the engineering community and with society at large, such as, being able to comprehend and write effective reports and design documentation, make effective presentations, give and receive clear instructions.

PO11: PROJECT MANAGEMENT AND FINANCE: Demonstrate knowledge and understanding of the engineering and management principles and apply these to one's own work, as a member and leader in a team, to manage projects and in multidisciplinary environments.

PO12: **LIFE-LONG LEARNING**: Recognize the need for, and have the preparation and ability to engage in independent and life-long learning in the broadest context of technological change

Head of the Department
Department of H&S
SRI INDU INSTITUTE OF ENGG & TECH

heriouda(M) Ibrahimoatnam (M) R.R. Dist-501 516

B. Tech. in CSE (CYBER SECURITY) COURSE STRUCTURE, I YEAR SYLLABUS (BR22 Regulations) Applicable from Academic Year: 2022-23 Batch

I Year II Semester

S. No.	Course Code	Course Title	L	T	P	Credits
1.	MA101BS	Matrices and Calculus	3	1	0	4
2.	CH103BS	Engineering Chemistry	3	1	0	4
3.	CS103ES	Programming for Problem Solving	3	0	0	3
4.	EE101ES	Basic Electrical Engineering	2	0	0	2
5.	ME101ES	Computer Aided Engineering Graphics		0	4	3
6.	CS106ES	Elements of Computer Science & Engineering	0	0	2	1
7.	CH106BS	Engineering Chemistry Laboratory	0	0	2	1
8.	CS107ES	Programming for Problem Solving Laboratory	0	0	2	1
9.	EE102ES	Basic Electrical Engineering Laboratory		0	2	1
		Induction Program				
		Total	12	2	12	20

I Year II Semester

S. No.	Course Code	Course	L	Т	P	Credits
1.	MA201BS	Ordinary Differential Equations and Vector Calculus	3	1	0	4
2.	AP202BS	Applied Physics	3	1	0	4
3.	ME202ES	Engineering Workshop	0	1	3	2.5
4.	EN204HS	English for Skill Enhancement	2	0	0	2
5.	EC201ES	Electronic Devices and Circuits	2	0	0	2
6.	AP205BS	Applied Physics Laboratory	0	0	3	1.5
7.	CS201ES	Python Programming Laboratory	0	1	2	2
8.	EN207HS	English Language and Communication Skills Laboratory	0	0	2	1
9.	CS203ES	IT Workshop	0	0	2	1
10.	*MC201ES	Environmental Science	3	0	0	0
		Total	13	4	12	20

APPLIED PHYSICS LABORATORY

(Course Code: AP205BS)

B.Tech. I Year II Sem.

L T P C 0 0 3 1.5

Course Objectives: The objectives of this course for the student to

- 1. Capable of handling instruments related to the Hall effect and photoelectric effect experiments andheir measurements.
- 2. Understand the characteristics of various devices such as PN junction diode, Zener diode, BJT,LED, solar cell, lasers and optical fiber and measurement of energy gap and Resistivity of semiconductor materials.
- 3. Able to measure the characteristics of dielectric constant of a given material.
- 4. Study the behavior of B-H curve of ferromagnetic materials.
- 5. Understanding the method of least squares fitting.

Course Outcomes: The students will be able to:

- 1. Know the determination of the Planck's constant using Photo electric effect and identify the material whether it is n-type or p-type by Hall experiment.
- 2. Appreciate quantum physics in semiconductor devices and microelectronics.
- 3. Gain the knowledge of applications of dielectric constant.
- 4. Understand the variation of magnetic field and behavior of hysteresis curve.
- 5. Carried out data analysis.

LIST OF EXPERIMENTS:

- 1. Determination of work function and Planck's constant using photoelectric effect.
- 2. Determination of Hall co-efficient and carrier concentration of a given semiconductor.
- 3. Characteristics of series and parallel LCR circuits.
- 4. V-I characteristics of a p-n junction diode and Zener diode
- 5. Input and output characteristics of BJT (CE, CB & CC configurations)
- 6. a) V-I and L-I characteristics of light emitting diode (LED)
 - b) V-I Characteristics of solar cell
- 7. Determination of Energy gap of a semiconductor.
- 8. Determination of the resistivity of semiconductor by two probe method.
- 9. Study B-H curve of a magnetic material.
- 10. Determination of dielectric constant of a given material
- 11. a) Determination of the beam divergence of the given LASER beam
 - b) Determination of Acceptance Angle and Numerical Aperture of an optical fiber.
- 12. Understanding the method of least squares torsional pendulum as an example.

Note: Any 8 experiments are to be performed.

REFERENCE BOOK:

S. Balasubramanian, M.N. Srinivasan "A Text book of Practical Physics"- S Chand Publishers, 2017.

(An Autonomous Institution under UGC)

Accredited by NAAC with A+ Grade, Recognized under 2(f) of UGC Act 1956. (Approved by AICTE, New Delhi and Affiliated to JNTUH, Hyderabad Khalsa Ibrahimpatnam, Sheriguda(V), Ibrahimpatnam(M), Ranga Reddy Dist., Telangana – 501 510 https://siiet.ac.in/

SEMESTER: II CLASS: CSE(CYBER SECURITY) A. Y: 2022-23

Course Outcomes

After completing this course, the student will be able to:

C126.1	Demonstrate Photoelectric Effect and Determine the work	Function and planks
	constant.	(Understanding)L2
C126.2	Analyzing the properties of semiconductor materials.	(Analyzing)L4
C126.3	Illustrate the characteristics of semiconductors devices.	(Understanding)L2
C126.4	Construct LCR and RC circuit and evaluate their chara-	acteristics
	(Ард	olying)L3
C126.5	Find the properties of Laser and Optical fibre.	(Remembering) L1
C126.6	Explain the properties of least squares, Dielectric and magn	netic materials.
		(Evoluating) I 5

(Evaluating) L5

Mapping of course outcomes with program outcomes:

High -3 Medium -2 Low-1

PO/CO	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO 10	PO 11	PO 12	PSO 1	PSO 2
C126.1	3	2	-	-	-	-	-	-	-	-	-	1	-	-
C126.2	3	2	-	-	-	-	-	-	-	-	-	1	-	-
C126.3	3	2	-	-	-	-	-	-		-	-	1	-	-
C126.4	3	2	-	-	-	-	-	-	-	-	-	1	-	-
C126.5	3	2	-	-	-	-	-	-	-	-	-	1	-	-
C126.6	3	2	-	-	-	-	-	-	-	-	-	1	-	-
AVE	3	2	-	-	-	-	-	-	-	-	-	1	-	-



(An Autonomous Institution under UGC)

Accredited by NAAC with A+ Grade, Recognized under 2(f) of UGC Act 1956.

(Approved by AICTE, New Delhi and Affiliated to JNTUH, Hyderabad

Khalsa Ibrahimpatnam, Sheriguda(V), Ibrahimpatnam(M), Ranga Reddy Dist., Telangana – 501 510

https://siiet.ac.in/

MAPPING OF EXPERIMENT OUTCOMES WITH CO/PO'S/PSO

EXPERIMENT OBJECTIVES	EXPERIMENT OUTCOMES	CO	PO'S
To determine the work function "φ" of a metal.	The student determines the work function in a given material using photoelectric effect	C126.1	PO1, PO2, PO12
To determine the Hall voltage developed across the sample material. To calculate the Hall coefficient and the carrier concentration of the sample material	The student determines the hall voltage across the given sample and calculates the hall coefficient	C126.2	PO1, PO2, PO12
To study the frequency response and to find resonant frequencies of L-C-R series and parallel Circuits.	The student studies the frequency response and to find resonant frequencies of L-C-R series and parallel Circuits.	C126.4	PO1, PO2, PO12
To draw the characteristics of p-n junction Zener diode	The student draws the characteristics of p-n junction and Zener diodes	C126.3	PO1, PO2, PO12
Observe the i/p and o/p characteristics of BJT (CE, CB and CC)	The student observes the characteristics of BJT (CE, CB and CC)	C126.3	PO1, PO2, PO12
1.To Plot the V/I characteristics of Solar Cell2.To study the volt-ampere characteristics of a given LED source	The student can able to plot the V/I characteristics of Solar Cell, LED	C126.3	PO1, PO2, PO12
To determine the energy gap of a junction diode	The student will be able to evaluate the energy gap between two allowed bands for isolated atoms and recognizing the resistivity of semiconductor varies with temperature.	C126.2	PO1, PO2, PO12

To determine the resistivity of semiconductor by two probe method.	The student will determine the resistivity of semiconductor by two probe method.	C126.2	PO1, PO2, PO12
To study B-H of a magnetic material	The student will study B-H of a magnetic material	C126.6	PO1, PO2, PO12
To determine the dielectric constant of a given material	The student will determine the dielectric constant	C126.6	PO1, PO2, PO12
To determine the beam divergence of the given LASER beam and Numerical Aperture of an optical fiber	The student will determine the wave length of laser source using single slit diffraction grating.	C126.5	PO1, PO2, PO12
Understanding the method of Least squares – torsional pendulum	The student Understanding the method Least squares – torsional pendulum	C126.6	PO1, PO2, PO12
To study the Charging and Discharging of a Capacitor	The student studies the Charging and Discharging of a Capacitor/Condenser	C126.5	PO1, PO2, PO12



(An Autonomous Institution under UGC)

Accredited by NAAC with A+ Grade, Recognized under 2(f) of UGC Act 1956. (Approved by AICTE, New Delhi and Affiliated to JNTUH, Hyderabad) KhalsaIbrahimpatnam, Sheriguda(V), Ibrahimpatnam(M), Ranga Reddy Dist., Telangana – 501 510 https://siiet.ac.in/

Class: CYBER SECURITY

Semester: II

W.E.F-03-04-2023

LH:-D-207

	I 9:40- 10:30	II 10:30 - 11:20	III 11:20- 12:10	12:10- 12.45	IV 12.45- 1.35	V 1.35- 2.25	VI 2.25- 3.15	VII 3.15-4.00
MON	ENG	AP	ODE	L	PY	THON LA	В	EWS(T)/ PYTHON LAB(T)
TUE	AP	ENG	ENG	U	ES	ODE	EDC	LIBRARY
WED	EW	S/ELCS LA	В	N C	AP	ODE	ENG	ES
THU	EDC	AP	ES	н	EW	S/ELCS L	AB	ODE(T) /AP(T)
FRI	EDC	ODE	ENG		ITWS/AP LAB			AP(T) /ODE(T)
SAT	רו	ΓWS/AP LAB			ODE AP EDC		PYTHON LAB(T)/ EWS(T)	

Course Code	Course Name	Name of the Faculty	Course Code	Course Name	Name of the Faculty
MA201BS	ODE-Ordinary Differential Equations & Vector Calculus	CH.SARITHA	AP205BS	APLAB-Applied Physics Laboratory	Dr.B.NAGALAKSHMI/B .SANTHI/M.MANISHA/ M.JANAIAH
AP202BS	AP-Applied Physics	Dr.B.NAGALAKSHMI	CS201ES	Python Programming Laboratory	P.BALU/M.TEJASWI
EN204HS	ENG- English for Skill Enhancement	S.SWAPNA	EN207HS	ELCS LAB-English Language and Communication Skills Laboratory	S.SWAPNA/D.ANAND RAO
EC201ES	EDC-Electronics Devices and Circuits	B.ASHWINI	CS203ES	ITWS-IT Workshop	B.RAJITHA/N.KEERTHI CHANDANA
ME202ES	EWS-Engineering Workshop	MVB.KALYAN/B.SR INU NAIK	MC201ES	ES-Environmental Science	G.VIJAY

Time Pable Coordinator

Head of The Department
Solution Indu Institute of Engg. & Tech
Main Road, Sheriguda(V
Ibrahimpatnam(M), R.R. Dist,
Telangana-501 510

TO ENGINEERING TO THE PROPERTY OF THE PROPERTY

SRI INDU INSTITUTE OF ENGINEERING AND TECHNOLOGY

(An Autonomous Institution under UGC)

Accredited by NAAC with A+ Grade, Recognized under 2(f) of UGC Act 1956.

(Approved by AICTE, New Delhi and Affiliated to JNTUH, Hyderabad)

Khalsa Ibrahimpatnam, Sheriguda(V), Ibrahimpatnam(M), Ranga Reddy Dist., Telangana – 501 510

https://siiet.ac.in/

AP Lab External Question Paper

A.Y: 2022-23 SEM-II Branch: CYBER SECURITY DATE: 22-08-23(FN)

- 1. Plot the V –I Characteristics of LED.
- 2. Derive the values of i) Resonance Frequency ii) Band width iii) Quality Factor of the given LCR circuit.
- 3. Determine the work function of given metal by using photoelectric effect.
- 4. Determine the beam divergence of the given LASER light.
- 5. Draw the V-I characteristics of P-N junction diode.
- 6. Plot the V –I Characteristics of Zener diode.
- 7. Plot the V –I Characteristics of solar cell.
- 8. Determine the acceptance angle and numerical aperture of an optical fiber.
- 9. Find Hall coefficient and carrier concentration of a given semiconductor.
- 10. Determine the dielectric constant of a given material.
- 11. Determine the energy gap of a given semiconductor.



(An Autonomous Institution under UGC)

Accredited by NAAC with A+ Grade, Recognized under 2(f) of UGC Act 1956.

(Approved by AICTE, New Delhi and Affiliated to JNTUH, Hyderabad)

Khalsa Ibrahimpatnam, Sheriguda(V), Ibrahimpatnam(M), Ranga Reddy Dist., Telangana – 501 510

https://siiet.ac.in/

AP Lab External Time Table Examination Branch

A.Y.: 2022-23 SEM-II

DATE	Day	Branch Session		HT. No	Total No of Student s
19-08-23	SATURDAY	CSE-C	E-C AN 22X		61
21-08-23	MONDAY	CSE-B	CSE-B AN		65
22-08-23	TUESDAY	CS	FN	22X31A6201 TO 22X31A6262	62
23-08-23	WEDNESDAY	DS	FN	22X31A6701 TO 22X31A6764	62
24-08-23	THURSDAY	CSE-A	FN	22X31A0501 TO 22X31A0565	65

FN: 9.40 am to 12.25 pm AN: 1.00 pm to 4.00 pm

Head of the Department
Department of H&S
SRI INDU INSTITUTE OF ENGG & TECH
Periouda(N) Ibrahimostnam (M) R.R. Dist-501 516

Sri Indu Institute of Engineering & Tecr.

Sheriguda(Vill), Ibrahimpatnam R.R. Dist. Telangana-501 510.





(An Autonomous Institution under UGC)

Accredited by NAAC with A+ Grade, Recognized under 2(f) of UGC Act 1956. (Approved by AICTE, New Delhi and Affiliated to JNTUH, Hyderabad) Khalsa Ibrahimpatnam, Sheriguda(V), Ibrahimpatnam(M), Ranga Reddy Dist., Telangana – 501 510 https://siiet.ac.in/

AP Lab External Time Table with examiners

A.Y.: 2022-23 **SEM-II**

					Total	Re	emarks
Date	Day	Branch	Sessio n	HT.No	No of Stude nts	Internal Examiner	External Examiner
19-08-23	SATURDAY	CSE-C	AN	22X31A05D1 TO 22X31A05J1	61	B. SANTHI (9493978954)	Dr. B. Narsimha (9490356088)
21-08-23	MONDAY	CSE-B	AN	22X31A0566 TO 22X31A05D0	65	M. JANAIAH (9291513934)	Mrs. G. Sandhya (9441719540)
22-08-23	TUESDAY	CS	FN	22X31A6201 TO 22X31A6262	62	B. SANTHI (9493978954)	Dr. B. Narsimha (9490356088)
23-08-23	WEDNESDA Y	DS	FN	22X31A6701 TO 22X31A6764	62	M. JANAIAH (9291513934)	Mr. P. Venkatesh- (9014229680)
24-08-23	THURSDAY	CSE-A	FN	22X31A0501 TO 22X31A0565	65	P. SRINIVASA CHARY (9848662600)	Dr .B. Rajini Kanth (7893092879)

FN: 9.40 am to 12.25 pm AN: 1.00 pm to 4.00 pm

Head of the Department Department of H&S SRI INDU INSTITUTE OF ENGG & TECH

"eriguda(M) Ibrahimoatnam (M) R.R. Dist-501 516

PRINCIPAL

Sri Indu Institute of Engineering & Tech Sheriguda(Vill), Ibrahimpatnam

R.R. Dist. Telangana-501 510.

(UGC AUTONOMOUS INSTITUTION)

Accredited by NAAC A+ Grade, Recognized under 2(f) of UGC Act 1956.

(Approved by AICTE, New Delhi and Affiliated to JNTUH, Hyderabad)

Khalsa Ibrahimpatnam, Sheriguda(V), Ibrahimpatnam(M), Ranga Reddy Dist., Telangana – 501510

https://siiet.ac.in/

DEPARTMENT OF HUMANITIES AND SCIENCES

Lab Occupancy Time Table for AY 2022-2023

Class: IB. Tech Semester: II W.E.F-03-04-2023 LH: B-201

	1	2	3	12:10- 12:45	4	5	6	7
Period/ Day	9:40- 10:30	10:30-11:2	11:20- 12:10	12.43	12.45-1.35	1:35- 2.25	2:25- 3:15	3:15-4:00
Monday								
Tuesday	CSE-E	B(BATCH-II)		L				
Wednesday				U N C	CSI	E-C (BATCH	I-II)	
Thursday	M	AINTANANC	E	Н				
Friday	CS	E-A (BATCH-	II)		DATA S	CIENCE(BA	ATCH-1)	
Saturday	CYBER S	SECURITY(BA	ATCH-II)		DATA S	CIENCE(BA	TCH-1I)	

Head of the Department
Department of H&S
SRI INDU INSTITUTE OF ENGG & TECH
Periouda(^\) Ibrahimoatnam (\) R.R. Dist-501 516

PRINCIPAL
Sri Indu Institute of Engineering & Tech
Sheriguda(Vill), Ibrahimpatnam
R.R. Dist. Telangana-501 510.



(UGC AUTONOMOUS INSTITUTION)

Accredited by NAAC A+ Grade, Recognized under 2(f) of UGC Act 1956.

(Approved by AICTE, New Delhi and Affiliated to JNTUH, Hyderabad)

Khalsa Ibrahimpatnam, Sheriguda(V), Ibrahimpatnam(M), Ranga Reddy Dist., Telangana – 501510

https://siiet.ac.in/

DEPARTMENT OF HUMANITIES AND SCIENCES

Lab Occupancy Time Table for AY 2022-2023

Class: I B. Tech Semester: II W.E.F- 03-04-2023 LH: D-106

	1	2	3		4	5	6	7
Period/ Day	9:40- 10:30	10:30- 11:20	11:20- 12:10	12:10-	12.45- 1.35	1:35- 2.25	2:25- 3:15	3:15- 4:00
Monday	CSE-0	C (BATCH	-I)		CSE	E-B(BATCI	H-I)	
Tuesday					MA	INTANAN	CE	
Wednesday								
Thursday	CSE	-A(BATCH	[-I)					
Friday					CYBER SI	ECURITY(I	BATCH-I)	
Saturday								

Head of the Department
Department of H&S
SRI INDU INSTITUTE OF ENGG & TECH
Periouda(^\) Ibrahimoatnam (M) R.R. Dist-501 516

Sri Indu Institute of Engineering & Tech. Sheriguda(Vill), Ibrahimpatnam R.R. Dist. Telangana-501 510.

TOTAL STATE OF THE STATE OF THE

SRI INDU INSTITUTE OF ENGINEERING AND TECHNOLOGY

(UGC AUTONOMOUS INSTITUTION)

Accredited by NAAC A+ Grade, Recognized under 2(f) of UGC Act 1956.

(Approved by AICTE, New Delhi and Affiliated to JNTUH, Hyderabad)

Khalsa Ibrahimpatnam, Sheriguda(V), Ibrahimpatnam(M), Ranga Reddy Dist., Telangana – 501510

Website: https://siiet.ac.in/

APPLIED PHYSICS LAB

Course: B. Tech. I Year SUB CODE: AP205BS

Do's

- 1. Conduct in a responsible manner at all times in the laboratory.
- 2. Keep the work area clean, neat and free of any unnecessary objects.
- 3. Read the description, procedure and precautions of the experiment in the lab manual.
- 4. Place all sensitive electronic equipment safely on experimental table.
- 5. Before using the equipment one must read the labels and instructions carefully.
- 6. Set up and use the equipment as directed by the lab instructor.
- 7. Circuit connections are to be done only in power off mode.
- 8. Checkout the circuit connections before switching on the power.
- 9. Increase the power readings from minimum to maximum.
- 10. All procedures and experimental data should be recorded in the lab observation notebook.
- 11. Switch of the power in the circuit after completion of the experiment.
- 12. Any failure / break-down of equipment must be reported to the instructor.
- 13. Return the material properly after the completing the experiment.
- 14. Replace the materials in proper place after work.
- 15. Be careful when handling optical items like prisms, gratings etc.

Don't s

- 1. Do not wear loose clothing and do not hold any conducting materials in contact with skin when the power is on.
- 2. Do not touch any equipment or other materials in the laboratory area until instructed by instructor.
- 3. Do not modify or damage the laboratory equipment in any way unless the modification is directed by the instructor.
- 4. Do not handle electrical equipment and connections with wet hands.
- 5. Do not try to connect power in to the circuit without proper understanding of the circuit diagram.
- 6. Do not look directly into laser source.
- 7. Do not short any battery box or power supply, it may damage retina in your eye.
- 8. Never switch on the power button of the circuit until it has been approved by instructor

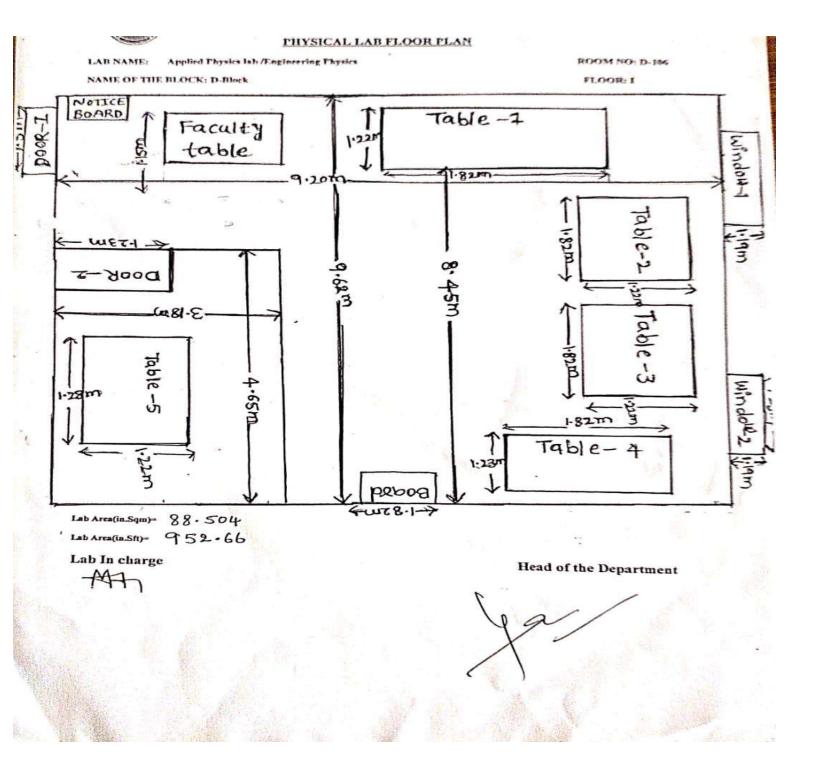
THE PROPERTY OF THE PROPERTY O

SRI INDU INSTITUTE OF ENGINEERING AND TECHNOLOGY

(An Autonomous Institution under UGC)

Accredited by NAAC with A+ Grade, Recognized under 2(f) of UGC Act 1956
(Approved by AICTE, New Delhi and Affiliated to JNTUH, Hyderabad)
Khalsa Ibrahimpatnam, Sheriguda (V), Ibrahimpatnam (M), Ranga Reddy Dist., Telangana – 501 510
Website: https://siiet.ac.in/

APPLIED PHYSICS LAB - 1 FLOOR PLAN





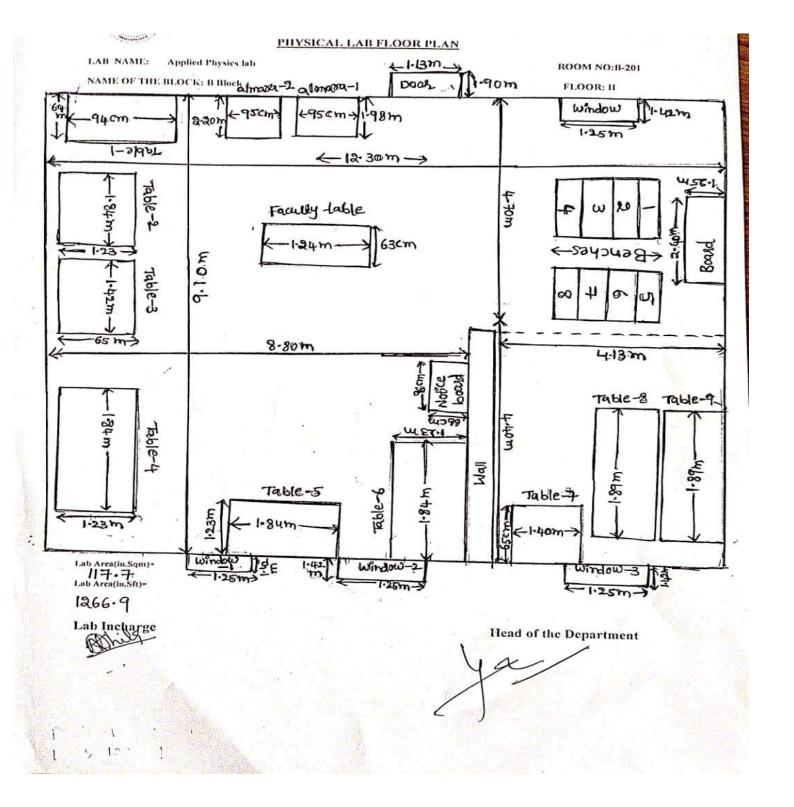
(An Autonomous Institution under UGC)

Accredited by NAAC with A+ Grade, Recognized under 2(f) of UGC Act 1956 (Approved by AICTE, New Delhi and Affiliated to JNTUH, Hyderabad)

Khalsa Ibrahimpatnam, Sheriguda (V), Ibrahimpatnam (M), Ranga Reddy Dist., Telangana – 501 510

Website: https://siiet.ac.in/

APPLIED PHYSICS LAB - 2FLOOR PLAN





(An Autonomous Institution under UGC)

Accredited by NAAC with A+ Grade, Recognized under 2(f) of UGC Act 1956
(Approved by AICTE, New Delhi and Affiliated to JNTUH, Hyderabad)
Khalsa Ibrahimpatnam, Sheriguda (V), Ibrahimpatnam (M), Ranga Reddy Dist., Telangana – 501 510
Website: https://siiet.ac.in/

Lab manual link

https://drive.google.com/file/d/1UTyWcm6bNeIw5qa 7CrdjE7PxMdQmHJ/view?usp=sharing

				G AND TECHN	OLOGY			
S ON ON	De	epartment of Hu	imanities and S	ciences				
(Eg)	1 (See 1)							
ORAm.	Course Outcom	e Attainment (Internal Exan	nination-1)				
Name o	of the faculty:	B SANTHI		Academic Year:	2022 - 23			
Branch	& Section:	CYBER SECU	JRITY	Examination:	LAB INTE	ERNAL	-I	
Lab Co	ourse Name:	APPLIED PHYSI	CS	Year/semester	I/II			
S.No	HT No.	R+O+A	V+V	E+E+R				
Max. Ma	rks ==>	10	10	10				
1	22X31A6201	8	6	9				
2	22X31A6202	10	4	8				
3	22X31A6203	10	5	10				
4	22X31A6204	10	5	10				
5 6	22X31A6205	10 10	<u>7</u>	10				
7	22X31A6206 22X31A6207	10	4	7				+
8	22X31A6207 22X31A6208	10	6	9				_
9	22X31A6209	10	4	9				1
10	22X31A6210	10	6	10	1			
11	22X31A6211	9	5	10				
12	22X31A6212	10	4	10				
13	22X31A6213	10	5	9				
14	22X31A6214	10	9	10				
15	22X31A6215	10	5	9	1			
16 17	22X31A6216	10 10	5 6	10 10				+
18	22X31A6217	10	3	7	 			
19	22X31A6218 22X31A6219	10	6	8				+
20	22X31A6219 22X31A6220	10	4	9				
21	22X31A6221	10	4	7				
22	22X31A6222	9	4	9				
23	22X31A6223	10	6	10				
24	22X31A6224	10	5	9				
25	22X31A6225	10	5	9				
26	22X31A6226	9	5	10				
27	22X31A6227	10 9	5	9	ļ			
28 29	22X31A6228 22X31A6229	10	7	8	 			-
30	22X31A6229 22X31A6230	10	6	7				-
31	22X31A6231	9	6	7				
32	22X31A6232	10	6	8				
33	22X31A6233	10	6	8				
34	22X31A6234	9	5	6				
35	22X31A6235	9	4	5				
36	22X31A6236	10	4	10				
37	22X31A6237	9	6	7	 			
38	22X31A6238	9	<u>3</u>	6				+
39 40	22X31A6239 22X31A6240	9	6	7	 			+
41	22X31A6240 22X31A6241	10	8	10	1			
42	22X31A6241 22X31A6242	9	4	7	1			
43	22X31A6243	10	5	9				
44	22X31A6244	9	6	5				
45	22X31A6245	10	9	10				
46	22X31A6246	10	5	10				
47	22X31A6247	10	7	10				
48	22X31A6248	10	5	9 7	 			
49	22X31A6249	10	6		-			
50 51	22X31A6250 22X31A6251	10	5	9	 			+
52	22X31A6251 22X31A6252	10	5	7				+
53	22X31A6252 22X31A6253	10	8	10	1			+
54	22X31A6254	10	5	10	1			
55	22X31A6255	10	6	9				
56	22X31A6256	10	4	10				
57	22X31A6257	10	5	9				
58	22X31A6258	10	6	9				
59	22X31A6259	9	5	7	ļ			
60	22X31A6260	9	3	8				
61 62	22X31A6261 22X31A6262	10	7 5	9				

CO-6	Internal 1 Ex	• • •	<u> </u>	3		
CO-5						
CO-4						
CO-3	100%	97%	98%	3	3	60%
CO-2	100%	97%	98%	3	2	50%
CO-1	100%	97%	98%	3	1	40%
СО	Intrnal practica	E+E+R	OveralI	Level	Attainmen	1
1-2-0						
CO - 6						
CO - 4 CO - 5				+		
CO - 3 CO - 4	100%	100%	97%			
CO - 2	100%	100%	97%			
CO - 1	100%	100%	97%			
CO 1		1000/	070/			
CO - 6						
CO - 5						
CO - 4	1	1	1			
CO - 3	Y	Y	Y			
CO - 2	Y	Y	Y			
CO - 1	Y	Y	Y			
O Mapping with Exam Qu	uestions:					
ercentage of students cored more than target	10070	41 /0	9170			
	100%	41%	97%			
Jumber of students	61	61	61			
erformed above the target		23	39			
Jumber of students	61	25	59			
arget set by the faculty /	6.00	6.00	6.00			

SRI INDU INSTITUTE OF ENGINEERING AND TECHNOLOGY Department of Humanities and Sciences rse Outcome Attainment (Internal Examination-2) 2022 - 23 Name of the faculty: **B SANTHI** Academic Year: Branch & Section: CYBER SECURITY LAB INTERNAL-II Examination: Lab Course Name: APPLIED PHYSICS Year/semester I/IIHT No. E+E+RS.No V+VR+O+Appt Max. Marks ==> 22X31A6201 22X3<u>1A6202</u> 22X31A6203 22X31A6204 22X31A6205 22X31A6206 22X31A6207 22X31A6208 22X31A6209 22X31A6210 22X31A6211 22X31A6212 22X31A6213 22X31A6214 22X31A6215 22X31A6216 22X31A6217 22X3<u>1A6218</u> 22X31A6219 Q 22X31A6220 22X31A6221 22X31A6222 22X31A6223 22X31A6224 22X31A6225 22X31A6226 22X31A6227 22X31A6228 22X31A6229 22X31A6230 22X31A6231 22X31A6232 22X31A6233 22X31A6234 22X31A6235 22X31A6236 22X31A6237 22X31A6238 22X31A6239 22X31A6240 22X31A6241 22X31A6242 22X31A6243 22X31A6244 22X31A6245 22X31A6246 22X31A6247 22X31A6248 22X31A6249 22X31A6250 22X31A6251 22X31A6252 22X31A6253 22X31A6254 22X31A6255 22X31A6256 22X31A6257 22X31A6258 22X31A6259 22X31A6260 22X31A6261

22X31A6262

arget set by the faculty /	6.00	6.00	6.00	6.00			
umber of students	61	29	46	62			
erformed above the target	 			+			
umber of students tempted	61	61	61	62			
ercentage of students cored more than target	100%	48%	75%	100%			
O Mapping with Exam Que	estions:						
CO - 1							
CO - 2							
CO - 3							
CO - 4	Y	Y	Y	Y			
CO - 5	Y	Y	Y	Y			
CO - 6	Y	Y	Y	Y			
O Attainment based on Ex	am Questions:						
CO - 1							
CO - 2							
CO - 3							
CO - 4	100%	48%	75%	75%			
CO - 5	100%	48%	75%	75%			
CO - 6	100%	48%	75%	75%			
СО	Intrnal practical	E+E+R	ppt	OveralI	Level	Attainme	nt Level
CO-1	1					1	40%
CO-2						2	50%
CO-3						3	60%
CO-4	74%	75%	75%	75%	3		
CO-5	74%	75%	75%	75%	3		
CO-6	74%	75%	75%	75%	3		
	Internal 2 Ex				3		
Attaininelli (ammati OI	1) —		3		

Sono

Number of successful students

Attainment level

Percentage of students scored more than target

SRI INDU INSTITUTE OF ENGINEERING AND TECHNOLOGY

Department of Humanities and Sciences

Course	Outcome	Attainment ((University	Examinations)

Name of the faculty: B SANTHI Academic Year: 2022 - 23

Branch & Section: CYBER SECURITY Year / Semester: I/II

Lab Course Name: APPLIED PHYSICS

Lab C	ourse Name:	APPLIED PHYSICS				
S.No	Roll Number	Marks Secured		S.No	Roll Number	Marks Secured
1	22X31A6701	30		35	22X31A6235	28
2	22X31A6702	33		36	22X31A6236	52
3	22X31A6703	48		37	22X31A6237	52
4	22X31A6704	42		38	22X31A6238	24
5	22X31A6705	53		39	22X31A6239	33
6	22X31A6706	50		40	22X31A6240	46
7	22X31A6707	35		41	22X31A6241	57
8	22X31A6708	52		42	22X31A6242	30
9	22X31A6709	28		43	22X31A6243	50
10	22X31A6710	54		44	22X31A6244	33
11	22X31A6711	48		45	22X31A6245	54
12	22X31A6712	58		46	22X31A6246	42
13	22X31A6713	46		47	22X31A6247	58
14	22X31A6714	54		48	22X31A6248	35
15	22X31A6715	35		49	22X31A6249	50
16	22X31A6716	47		50	22X31A6250	
17	22X31A6717	56		51	22X31A6251	52
18	22X31A6718	50		52	22X31A6252	40
19	22X31A6719	30		53	22X31A6253	60
20	22X31A6720	45		54	22X31A6254	55
21	22X31A6721	50		55	22X31A6255	52
22	22X31A6722	40		56	22X31A6256	42
23	22X31A6723	58		57	22X31A6257	40
24	22X31A6724	31		58	22X31A6258	56
25	22X31A6725	46		59	22X31A6259	48
26	22X31A6726	35		60	22X31A6260	52
27	22X31A6727	31		61	22X31A6261	57
28	22X31A6728	26		62	22X31A6262	43
29	22X31A6729	29				
30	22X31A6730	29				
31	22X31A6731	25				
32	22X31A6733	42				
33	22X31A6734	47				
34	22X31A6234	26				
	verage mark		43		Attainment Level	% students
Number	of students perfor	med above the target	33		1	40%
T 1	C C 1 · ·				i e	i

61

54%

3

2

3

50%

60%

S AMA	Departme	ent of Humanities	and Scier	ices	
		Course Ou	itcome A	<u>tainment</u>	
STOCK SE THE STOCK					
Name of the faculty	B SANT	HI		Academic Year:	2022 - 23
Branch & Section:	CYBER	SECURITY		Year / Semester:	I/II
Lab Course Name:	APPLIED	PHYSICS			
Course Outcomes	1st Internal Exam	2nd Internal Exam	Internal Exam	University Exam	Attainment Level
CO1	3.00		3.00	3.00	3.00
CO2	3.00		3.00	3.00	3.00
CO3	3.00		3.00	3.00	3.00
CO4		3.00	3.00	3.00	3.00
CO5		3.00	3.00	3.00	3.00
CO6		3.00	3.00	3.00	3.00
Inter	nal & Univ	ersity Attainment:	3.00	3.00	
		Weightage	70%	30%	
CO Attainment for the	course (In	ternal, University)	2.10	0.90	
CO Attainment for t	the course	(Direct Method)		3.00	

SRI INDU INSTITUTE OF ENGINEERING & TECHNOLOGY Department of Humanities and Sciences **Program Outcome Attainment (from Course)** Name of Faculty: Academic Year: 2022 - 23 **B SANTHI** Branch & Section: **CYBER SECURITY** Year / Semester: I/II Course Name: APPLIED PHYSICS **CO-PO mapping** PO1 PO2 PO3 PO4 PO5 PO9 PO10 PO11 PO12 PSO1 PO6 PO7 PO8 PSO2 3 2 CO1 3 2 CO2 1 3 2 1 CO3 3 2 CO4 3 1 2 CO5 3 2 CO6 Course |3.00 | 2.00 1.00 **Course Outcome Attainment** CO 3.00 CO1 3.00 CO2 3.00 CO3 3.00 **CO4** 3.00 CO5 3.00 **CO6** Overall course attainment level 3.00 **PO-ATTAINMENT** PO1 PO2 PO3 PO4 PO5 PO6 PO7 PO8 PO9 PO10 PO11 PO12 PSO1 PSO2 co Attainm 3.00 2.00 ent 1.00 CO contribution to PO - 33%, 67%, 100% (Level 1/2/3)